NSN 5980-00-148-4459

Light Emitting Diode - Page 1 of 1



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Inclosure Material:
Plastic
Internal Configuration:
Point contact
Internal Junction Configuration:
Pn
Mounting Method:
Terminal
Semiconductor Material:
Gallium arsenide phosphide
Voltage Rating In Volts Per Characteristic:
3.0 reverse voltage, dc
Current Rating Per Characteristic:
40.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
80.0 milliwatts total device dissipation
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0